

**Cascadable Amplifier
10 to 300 MHz**

A87-2/ SMA87-2

V3

Features

- LOW NOISE FIGURE: 3.0 dB (TYP.)
- HIGH FREQUENCY: 15 mA @ +5 Vdc (TYP.)
- HIGH OUTPUT POWER AT 5 VOLTS: +11 dBm (TYP.)
- LOW VSWR: <1.5:1 (TYP.)

Description

The A87-2 RF amplifier is a discrete hybrid design, which uses thin film manufacturing processes for accurate performance and high reliability.

This single stage bipolar transistor feedback amplifier design displays impressive performance over a broadband frequency range. Use of an impedance transformer offers the benefit of high dynamic range and high efficiency.

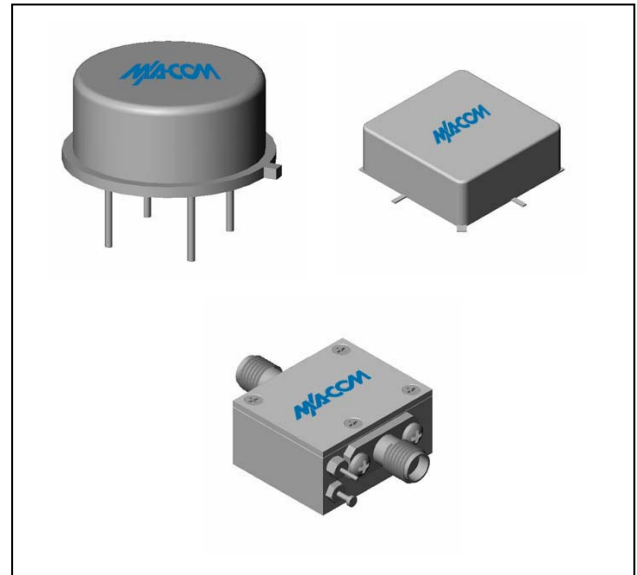
Both TO-8 and Surface Mount packages are hermetically sealed, and MIL-STD-883 environmental screening is available

Ordering Information

Part Number	Package
A87-2	TO-8
SMA87-2	Surface Mount
CA87-2 **	SMA Connectorized

** The connectorized version is not RoHs compliant.

Product Image



Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +5 V_{DC}$

Parameter	Units	Typical	Guaranteed	
		25°C	0° to 50°C	-54° to +85°C*
Frequency	MHz	5-350	10-300	10-300
Small Signal Gain (min)	dB	16.0	15.0	14.5
Gain Flatness (max)	dB	±0.2	±0.5	±0.8
Reverse Isolation	dB	20		
Noise Figure (max)	dB	2.9	3.5	4.0
Power Output @ 1 dB comp. (min)	dBm	11.0	9.0	8.5
IP3	dBm	+24		
IP2	dBm	+35		
Second Order Harmonic IP	dBm	+41		
VSWR Input / Output (max)		1.3:1 / 1.3:1	1.8:1 / 1.8:1	2.0:1 / 2.0:1
DC Current @ 5 Volts (max)	mA	15	17	18

Absolute Maximum Ratings

Parameter	Absolute Maximum
Storage Temperature	-62°C to +125°C
Case Temperature	+125°C
DC Voltage	+10 V
Continuous Input Power	+13 dBm
Short Term Input power (1 minute max.)	50 mW
Peak Power (3 µsec max.)	0.5 W
"S" Series Burn-In Temperature (case)	+125°C

Thermal Data: $V_{CC} = +5 V_{DC}$

Parameter	Rating
Thermal Resistance θ_{jc}	185°C/W
Transistor Power Dissipation P_d	0.034 W
Junction Temperature Rise Above Case T_{jc}	6°C

* Over temperature performance limits for part number CA87-2, guaranteed from 0°C to +50°C only.

